

Glass Axial Package

BAT42 BAT43

DO- 35

SILICON PLANAR SCHOTTKY DIODES

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General Purpose Metal to Silicon Diodes Featuring Very Low Turn-on Voltage and Fast Switching

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Repetitive Peak Reverse Voltage	V _{RRM}	30	V
Forward Current (DC)	*I _F	200	mA
Repetitive Peak Forward Current tp <u><</u> 1s d ≤0.5	*I _{FRM}	500	mA
Surge Non Repetitive Forward Current tp <u><</u> 10ms	*I _{FSM}	4.0	А
Power Dissipation T _a =65 ^o C	P _D	200	mW
Storage Temperature Range	T _{stg}	- 65 to +150	°C
Junction Temperature	Τ _j	- 65 to +125	°C
Maximum Lead Temperature for Soldering during 10s at 4mm from case	TL	230	°C
THERMAL RESISTANCE			
Junction to Ambient in free air	*R _{th (j-a)}	300	°C/W

*On infinite heat sink with 4mm lead length

ELECTRICAL CHARACTERISTICS (T_i=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION		MIN	MAX	UNIT
Reverse Breakdown Voltage	V _{(BR)R}	I _R =100μΑ		30		V
Forward Voltage	**V _F	I _F =200mA	All Types		1.0	V
		I _F =10mA	BAT42		0.40	V
		I _F =50mA	BAT42		0.65	V
		I _F =2mA	BAT43	0.26	0.33	V
		I _F =15mA	BAT43		0.45	V
Reverse Current	**I _R	V _R =25V T _j =25⁰C V _R =25V T _j =100⁰C			0.5	μΑ
					100	μA

DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL TEST CONDITION N		MIN	MAX	UNIT	
Diode Capacitance	C _d	V _R =1V, f=1MHz	TYP 7.0		pF	
Reverse Recovery Time When Switched From	t _{rr}	I_F =10mA to I_R =10mA, measured at I_{RR} =1mA, R_L =100 Ω		5	ns	
Detection Efficiency	π_v	R_L =15K Ω , C_L =300pF, f=45MHz, V _I =2V	80		%	

Pulse test: tp=300ms d <2%

BAT42_43Rev300105E

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All dimensions are in mm.

DIM	MIN	МАХ
Α	25.40	—
В	3.03	4.44
С	0.46	0.56
D	1.52	2.29



On request also available in 26 mm Tape and Ammo Pack

Packing Detail

PACKAGE	STANDARDPACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size Oty Gr V		
DO-35 T&A	5K/ammo box	0.88 kg/5K pcs	10" x 3.5" x 3.5"	5.0K	12.7" x 12. 7" x 20"	125.0K	25 kgs

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Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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